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Plenary Speakers

Plenary 1: Memory - the N3XT Frontier....1

Wong Philip

Plenary 2: Device Modeling for Circuit Simulation in Nanometer

Technology.....2

Zhihong Liu

Plenary 3: Circuit Design in Nano-Scale CMOS Technologies.....3

Zhang Kevin

Plenary 4: Mixed-Signal Circuits for the Data-Driven World.....4

Boris Murmann

Invited Speakers

Invited Talk 1: Nanocarbon Via Interconnects.....5

Cary Yang

Invited Talk 2: Electrically Tunable Bandgaps in 2D Layered Materials.....N/A

Zhihong Chen

Invited Talk 3: MEMS Pressure Sensors for High-Temperature High-Pressure Downhole Applications.....N/A

Fan Zeng, Lei Lu, Yiming Zhang, Shichao Guo, Man Wong and Kevin Chau

Invited Talk 4: Manufacturing of Using Spray Method to Produce Solar Cell.....N/A

Po-Ying Chen

Invited Talk 6: Circuit Design of Physical Unclonable Function for Security Applications in Standard

CMOS Technology.....N/A

Byong-Deok Choi

Invited Talk 7: Design Guidelines of $\Sigma\Delta$ Modulators: From System to Chip and Application to Reconfigurable ADCs.....N/A José M. de La Rosa Toward High-Performance Electronics based on Carbon Nanomaterials.....N/A **Invited Talk 8:** Shu-Jen Han Scaling Challenges and Solutions beyond 10nm....N/A **Invited Talk 9:** Srinivasa Banna Advanced Physical Models in Widegap Device Simulation.....N/A **Invited Talk 10:** Simon Li, Gary Dolny and Yue Fue A Versatile Flicker Noise Measurement System and Its Applications in CMOS Process.....N/A **Invited Talk 11:** Zhijian (James) Ma and Zhihong Liu **Invited Talk 12:** Novel Electronic and Photonic Properties of Low-Symmetry Two-Dimensional Materials.....N/A He Tian, Huan Zhao and Han Wang **Invited Talk 13:** A Sub-0.5V Charge Pump Circuit for Resistive RAM (ReRAM) Enabled Low Supply Voltage Nonvolatile Logics and Nonvoaltile Processors.....N/A Meng-Fan Chang, Shin-Jang Shen, Yi-Lun Lu, Yih-Shan Yang, Jui-Yu Hung, Che-Wei Wu, Yan-Bing Jhang, Weihow Chen and Han-Wen Hu **Invited Talk 14:** Silicene: The Ultimate Atomic Scaling of Silicon.....N/A Akinwande Deji **Invited Talk 15:** Effects of Fin Width on Performance and Reliability for N- and P-type FinFETs.....N/A Yeh W.K. **Invited Talk 16:** Design Considerations for Power Efficient Continuous-time Delta-Sigma Converters.....N/A Pavan Shanthi **Invited Talk 17:** Material Characterization and Device Simulation of GeSn Alloys for Field-Effect Transistors Applications.....N/A Xu Jun **Invited Talk 18:** Highly Sensitive and Functional Photodetectors based on Silicon-On-Insulator.....N/A Inokawa Hiroshi **Invited Talk 19:** A New Generation 3D Printed On-Chip Energy Storage Devices.....N/A Yang Hui Ying

Technical Papers

Session W1	Nanoelectronics 1
Date / Time	3 August 2016 / 14:10 – 15:40
Session Chair	W. T. Ng and J. J. Liou

- Nanocarbon Via Interconnects (Invited Talk).....N/A
 Cary Yang
- A Novel Thin-Film Transistor Using Carbon Nanotubes as Both Channel and Electrodes.....13

 Peijian He, Yanyan Deng, Chun Chen and Min Zhang
- Electrical Performance of Multilayer MoS₂ Transistor with ALD HfTiO Gate Dielectric.....17 Ming Wen, J. P. Xu, L. Liu, Y. Huang, P. T. Lai and W. M. Tang
- Nanostructured TiO₂ Schottky Diode with Large Surface Area for Chemical Sensors.....21
 Wenhao Yan, Jerry Yu and Derek Ho

Session W2	Emerging Devices 1
Date / Time	3 August 2016 / 14:10 – 15:40

- Electrically Tunable Bandgaps in 2D Layered Materials (Invited Talk).....25
 Zhihong Chen
- Effect of Si-Delta Doping and Barrier Lengths on the Performance of Triple Barrier GaAs/AlGaAs Resonant Tunneling Diode.....30
 Man Mohan Singh and M. J. Siddiqui
- Analytical Drain Current Model for Long-Channel Double-Gate Negative Capacitance Junctionless Transistors Using Landau Theory.....35
 Chunsheng Jiang, Renrong Liang, Jing Wang and Jun Xu

Session W3	Sensors, Imagers and MEMS 1
Date / Time	3 August 2016 / 14:10 – 15:40

 MEMS Pressure Sensors for High-Temperature High-Pressure Downhole Applications (Invited Talk).....39

Fan Zeng, Lei Lu, Yiming Zhang, Shichao Guo, Man Wong and Kevin Chau

- CMOS Computational Pixel for Binary Temporal Optically Encoded High-Speed Imaging.....44
 Yi Luo, Nan Guo, Shahriar Mirabbasi and Derek Ho
- An Oscillator-based CMOS Magneto-Sensitive Biosensor with a Low Noise and Low Temperature Coefficient LDO Regulator.....48

Jinwen Geng, Lei Zhang, Cheng Zhu and He Qian

o Inductance to DC Resistance Ratio Optimization of On-Chip Closed-Core Spiral Power Inductors.....52
Shujie Chen, Yunkun Li and Rongxiang Wu

Session W4	Emerging Devices 2
Date / Time	3 August 2016 / 16:00 – 17:30

- Manufacturing of Using Spray Method to Produce Solar Cell (Invited Talk).....56
 Po-Ying Chen
- Quantum Ballistic Transport in Ultra-Small Silicon Channel Cylindrical Gate-All-Around Junction Less Nanowire Transistor Using NEGF Formalism.....62
 Md. Mohsinur Rahman Adnan, Md. Samzid Bin Hafiz, Nujhat Tasneem and Quazi D. M. Khosru
- The Immunity of Doping-Less Junctionless Transistor Variations Including the Line Edge Roughness.....66

Wenbo Wan, Haijun Lou, Ying Xiao and Xinnan Lin

Ultra-thin and Ultra-flexible Temperature /Strain Sensor with CNT Nanostrips.....70
 Yihao Chen, Bingwei Lu, Ying Chen and Xue Feng

Session W5	Novel Devices 1
Date / Time	3 August 2016 / 16:00 – 17:30

o **Bipolar Resistive Switching in Al/GO-PEDOT:PSS/Pt Memory Devices.....74**Hong Chao, Fang-Yuan Yuan, Huaqiang Wu, Ning Deng, Chongjie Wang and Rongshan Wei

 Near-Infrared Light Emitting Diode Array Based on Ordered Si Micropillar/InGaZnO-Nanofilm Heterojunctions.....78

Jin Wang, Renrong Liang, Libin Liu, Bolin Shan, Jing Wang and Jun Xu

Solar-Blind Deep-Ultraviolet Photodetector Based on the β-Ga₂O₃ Thin Film Grown on Annealed C-plane Sapphire Substrate.....82

Z. H. Wu, L. X. Qian, T. Sheng, Y. Y. Zhang and X. Z. Liu

Session W6	Digital 1
Date / Time	3 August 2016 / 16:00 – 17:30

 Circuit Design of Physical Unclonable Function for Security Applications in Standard CMOS Technology (Invited Talk).....86

Byong-Deok Choi

- Low Perfusion Algorithm used in Wearable Oximeter and Hardware Acceleration.....91
 Zhaoxia Zheng, Xufeng Wu, Xiaogang Zeng and Panting Jiang
- Voltage Comparison Based High Speed & Low Power Domino Circuit for wide Fan-in Gates.....96
 Pratosh Kumar Pal, Avaneesh Kumar Dubey, Sankit R. Kassa and Rajendra Kumar Nagaria
- Systolic Array Based VLSI Architecture For High Throughput 2-D Discrete Wavelet Transform.....100
 Hongda Wang and Chiu-Sing Choy

Session T1	Digital 2
Date / Time	4 August 2016 / 8:50 – 9:50

 A 0.68-to-1.44 GHz Low-Jitter All-Digital Phase-Locked Loop with A Novel PFD and A High Resolution DCO in 0.18μm CMOS.....104

Xiaoying Deng, Yanyan Mo, Xin Lin and Mingcheng Zhu

An Optimized Design of Reversible Magnitude and Signed Comparators.....108

A. N. Nagamani, Desik Rengarajan and Vinod K. Agrawal

Session T2	HV and Power Devices
Date / Time	4 August 2016 / 8:30 – 9:50

- A Novel Split-Gate Structure for 85V Application with Low Output Capacitance.....112
 Ye Tian, Zhuo Yang, Jincheng Zhou, Fangjuan Bian, Xin Tong, Jing Zhu, Weifeng Sun, Longxing Shi, Yuanzheng Zhu and Peng Ye
- O An Improved Structure to Enhance the Robustness of SiC Power MOSFETs for a Low R on,sp.....116

 Xintian Zhou, Ruifeng Yue, Gang Dai, Juntao Li and Yan Wang
- A Variation Laterl Doping Layer and Lightly Doped Region Compensated Superjunction LDMOS.....120
 Lixiao Liang, Haimeng Huang and Xingbi Chen
- o Modeling of High Voltage LDMOSFET using Industry Standard BSIM6 MOS Model.....124 Chetan Gupta, Harshit Agarwal, Yogesh S. Chauhan, Sourabh Khandelwal, Yen-Kai Lin, Chenming Hu and Renaud Gillon

Session T3	RF Devices and Circuits
Date / Time	4 August 2016 / 8:30 – 9:50

 High Power Performance AlGaN/GaN HEMT with 0.1μm Y-shaped Gate Encapsulated with Lowκ BCB.....128

Xinxin Yu, Jianjun Zhou, Yuechan Kong, Daqing Peng, Weibo Wang, Fangjin Guo, Haiyan Lu, Wen Wang, Cen Kong, Zhonghui Li and Tangsheng Chen

Measurement and Modeling Techniques for InP-Based HBT Devices to 220GHz.....132
 Haiyan Lu, Wei Cheng, Zhijiang Zhou, Oupeng Li, Bin Niu, Yuechan Kong, Tangsheng Chen

• A Reconfigurable UHF CMOS Voltage Multiplier.....136 Jingbin Jia, Marco Ho and Ka Nang Leung

A 66 to 76CUz E band ODLI with Amplifian Foodback OV

• A 66-to-76GHz E-band QPLL with Amplifier Feedback QVCO in 65-nm CMOS.....140 Xinxin Zhu, Lei Zhang, Yan Wang, and Zhiping Yu

Session T4	Analog 1
Date / Time	4 August 2016 / 10:10 – 12:00

 $\circ~$ Design Guidelines of $\Sigma\Delta$ Modulators: From System to Chip and Application to Reconfigurable ADCs (Invited Talk).....144

José M. de la Rosa

- A Fast Three-Level Feedback Technique in Continuous-Time Delta-Sigma Modulators.....149
 Debajit Basak, Daxiang Li, Zhongi Fu, Jiangpeng Wang, Zhang Yang and Kong-Pang Pun
- Electrostatic Energy Harvester Based on Charge-Trapping Nonvolatile Memory Structure.....153
 J.J. Shi and X.D. Huang
- A Five-Order Butterworth Low-Pass Filter with DC Offset Cancellation for WLAN Applications.....157
 Dongyang Yan, Lei Zhang, Li Zhang and Yan Wang

Session T5	Emerging Devices 3
Date / Time	4 August 2016 / 10:10 – 12:00

- Toward High-performance Electronics Based on Carbon Nanomaterials (Invited Talk).....161
 Shu-Jen Han
- Exposure Optimization for Multi-Bit Quanta Image Sensor with Ultra-Small Well Capacity.....165

 Ka Wai Cheung, Hiu Tung Wong and Derek Ho
- o High-Speed Disturbance-Free Nonvolatile Flip-Flop Based on Complementary Polarizers.....169
 Lianhua Qu, Zhenyu Zhao, Yao Wang, Huan Li, Haoyue Tang, Quan Deng and Peng Li
- Comparative Study of InGaZnO Thin-Film Transistors with Single and Dual NbLaO Gate Dielectric Layers.....173

J. Q. Song, P. T. Lai and X. D. Huang

Modeling of Fringe Current for Semiconductor-Extended Organic TFTs.....177
 H. M. Dipu Kabir, Zubair Ahmed, Remashan Kariyadan, Lining Zhang and Mansun Chan

Session T6	High Speed Circuits
Date / Time	4 August 2016 / 10:10 – 12:00

- Scaling Challenges and Solutions beyond 10nm (Invited Talk).....181
 Srinivasa Banna
- A 10GHz Analog Phase Interpolator Based on a Novel Quadrature Clock Generator.....187

 Xiaoting Zhi, Weixin Gai, Liangxiao Tang and Linqi Shi
- A Speculative Clock and Data Recovery Architecture for Multi-Gigabit/s Series Links.....191
 Tong Zhao, Weixin Gai, Liangxiao Tang, Linqi Shi, Xing Zhang, Tong Zhao, Weixin Gai, Liangxiao Tang
 and Linqi Shi
- Design of 20-Gb/s Four-Level Pulse Amplitude Modulation VCSEL Driver in 90-nm CMOS Technology.....195

Jhe-Yue Li, Jau-Ji Jou, Tien-Tsorng Shih, Chien-Liang Chiu, Jian-Chiun Liou and Hsin-Wen Ting

A 6.5-GHz Digitally-Controlled Oscillator with Supply Sensitivity of 0.0071%-f_{DCO}/1%-V_{DD}.....199

Jichao Huang, Weixin Gai, Liangxiao Tang, Linqi Shi, Tong Zhao and Xing Zhang

Session T7	Device Modeling and Simulation 1
Date / Time	4 August 2016 / 14:00 – 15:50

- Advanced Physical Models for Widegap Device Simulation (Invited Talk).....203
 Simon Li, Gary Dolny and Yue Fue
- Linearity Performance of Gate Metal Engineered (GME) Omega Gate-Silicon Nanowire MOSFET: A TCAD Study.....208
 Neha Gupta, Arshiya Vohra and Rishu Chaujar
- Comparison of Ultra Low Power Junctionless and Inversion-Mode FinFETs with Compact Model.....212

Zebang Guo and Yan Wang

 Modeling of Threshold Voltage for Operating Point using Industry Standard BSIM-IMG Model.....216

Pragya Kushwaha, Rahul Agarwal, Harshit Agarwal, Yogesh Singh Chauhan, Sourabh Khandelwal, Juan P. Duarte, Yen-Kai Lin, Huan-Lin Chang and Chenming Hu

Session T8	Device Physics and Reliability
Date / Time	4 August 2016 / 14:00 – 15:30

 A Versatile Flicker Noise Measurement System and Its Applications in CMOS Process (Invited Talk).....220

Zhijian (James) Ma and Zhihong Liu

- Sneak-path Based Test for 3D Stacked One-Transistor-N-RRAM Array.....226
 Qiang Zhang, Xiaole Cui, Xiaoyan Xu, Xin'an Wang, Zhi Ma and Shengming Zhou
- Consistent Model of NBTI with Low Drain Voltage in P-MOSFETs.....230
 Shucheng Gao, Chenyue Ma and Xinnan Lin

Session T9	Novel Device 1
Date / Time	4 August 2016 / 14:00 – 15:50

 Novel Electronic and Photonic Properties of Low-Symmetry Two-Dimensional Materials (Invited Talk).....234

Han Wang and He Tian

 Quantum Correction in AlGaN/GaN Transistor Simulations Using Modified Local Density Approximation (MLDA).....239

Hiu Yung Wong, Oleg Penzin, Nelson Braga and R. V. Mickevicius

 Metamateral Enhanced Folded Waveguide Slow Wave Structure for Millimeter Wave Traveling Wave Tube Amplifier.....243

Jin Qin, Lei Zhang and Liu Chao

Modeling of Source/Drain Access Resistances and their Temperature Dependence in GaN HEMTs.....247
Sudip Ghosh, Sheikh Aamir Ahsan, Yogesh Singh Chauhan and Sourabh Khandelwal

Session	Poster
Date / Time	4 August 2016 / 15:50 – 17:40

- A 4.95mW 114dB SNDR Delta-Sigma Modulator Based on SC Circuits for Audio Chip.....251
 Hengdi Wu, Menglian Zhao, Xiaolin Yang, Xiaobo Wu and Su Hanyang
- Mobility Variation and Threshold Voltage Shift Immunized Amorphous-Indium-Gallium-Zinc-Oxide Pixel Circuit.....255

Zhiqiang Liao, Hesheng Lin, Binjie Liu and Min Zhang

- Adjustable Duty Cycle ASK Demodulator for Passive UHF RFID Tags.....259
 Yi Miao, Jiancheng Li, Hongyi Wang, Lei Cai, Yu Xiao, Li Yang and Miaoxia Zheng
- A 16-channel 12-bit Rail-to-Rail Successive Approximation Register ADC for AFEs.....263

 Yifan Jiang, Jianxiong Xi, Lenian He and Kexu Sun
- A Floating High-Voltage Level Shifter Used in A Pre-charge Circuit for Large-size AMOLED Displays.....267

Fangfang Yang, Cuicui Wang, Hing-Mo Lam, Qiang Zhao, Jia Fan and Shengdong Zhang

- An Asynchronous GFSK Demodulator for Automatic Meter Reading.....271

 Yuxuan Liu, Guanghua Wu, Hong Chen and Anping He
- A Low-Power Third-Order ΔΣ modulator Using Ring Amplifiers with Power-Saving Technique.....275
 Alexis Gryta, Takuma Suguro and Hiroki Ishikuro
- A 0.6V Standard Cell Library in 40nm CMOS for Near-threshold Computing.....279

 Jintao Li, Bo Pang, Ming Liu, Yuxuan Liu and Hong Chen
- A 0.32uW Physically Unclonable Fuction with BER <1.18E-5 Using Current Starved Inverters.....283 Yinxuan Lyu, Jianhua Feng, Hongfei Ye, Chunhua He and Dunshan Yu
- Adjustable Lumped Impedance Mismatching Compensation Circuit.....287
 Xiaomeng Zhang, Shuo Li and Saiyu Ren
- 2.4GHz 20Mb/s FSK Receiver Front-End and Transmitter Modulation PLL Design for Energy-Efficient Short-Range Communication.....291

Ranran Zhou, Yining Zhang, Woogeun Rhee and Zhihua Wang

Design of an Optimized CMOS Series-Parallel Coupled LC Quadrature Phase Oscillator.....295
 Sivaramakrishna Rudrapati, Sumit Emekar and Shalabh Gupta

 Design of Novel Digital GFSK Modulation and Demodulation System for Short-range Wireless Communication Application.....299

Xitian Long, Zhe Zheng, Xueping Jiang, Jinghong Guo, Guanghua Wu, Yanyi Meng, Hong Chen and Yuxuan Liu

 Improved Reliability of High-Voltage VDMOS with Reduced Mask Layers Through Optimized Edge Termination (Device Reliability).....303

Jen-HaoYeh, Yi-Rong Tu, Wan-Wen Tseng, Ming-Nan Chuaug, Pi-Feng Cheng, Chiung-Feng Chou and Chih-Fang Huang

- Simple leakage Current and 1/f Noise Expressions for Polycrystalline Silicon Thin-Film Transistors.....307

 Hongyu He, Wanling Deng, Yuan Liu, Xinnan Lin, Xueren Zheng and Shengdong Zhang
- A Vision Chip Architecture for Image Recognition Based on Improved Convolutional Neural Network.....310

Jijia Guo, Xin'an Wang, Jipan Huang, Yue Tang, Boyang Song, Jipeng Liu, Haifang Lu and Zhiqiang Yang

 An Algorithm of Training Sample Selection for Integrated Circuit Device Modeling Based on Artificial Neural Networks.....314

Zhiyuan Zhang, Xiaole Cui, Xinnan Lin and Lining Zhang

- The Effects of O₂ Annealing on the Characteristics of IGMO-based UV Photodetector.....318 Y. Y. Zhang, L. X. Qian, Z. H. Wu and X. Z. Liu
- Analysis of Factors in Phase Array Antenna and RF Units on System Performance of the OFDM PHY of IEEE 802.11ad Standard.....322

Jin Qin, Lei Zhang, Li Zhang and Yan Wang

 A 14-bit Column-Parallel Two-Step SA ADC with On-Chip Scaled Reference Voltages Self-Calibration for CMOS Image Sensor.....326

Jingyuan Chen, Jianxiong Xi, Lenian He, Kexu Sun and Ning Xie

- Tube Size Effect of Anodized Alumnium Oxide Template Based Gas Sensor.....330
 Huayu Hu, Zhipeng Kang, Xiaojin Zhao and Xiaofang Pan
- o Glove-Based Hand Gesture Recognition Sign Language Translator using Capacitive Touch Sensor.....334 Kalpattu S. Abhishek, Lee Chun Fai Qubeley and Derek Ho
- o Improved Hydrogen-Sensing Performance of Pd/WO₃/SiC Schottky Diode by La Doping.....338 Y. Liu, P. T. Lai and W. M. Tang

Session T10	Memory Technology & Dielectrics
Date / Time	4 August 2016 / 16:10 – 17:40

- A Sub-0.5V Charge Pump Circuit for Resistive RAM (ReRAM) Enabled Low Supply Voltage Nonvolatile Logics and Nonvoaltile Processors (Invited Talk).....342
 Meng-Fan Chang, Shin-Jang Shen, Yi-Lun Lu, Yih-Shan Yang, Jui-Yu Hung, Che-Wei Wu, Yan-Bing Jhang, Weihow Chen and Han-Wen Hu
- o A Low Power Selector-less Crossbar Array with Complementary Resistive-Switching Memory.....346

 Jang-Woo Ryu and Kee-Won Kwon
- o Improved Electrical Properties of GaAs MOS Capacitor by using HfLaON Passivation Layer.....350 L. N. Liu, H. W. Choi, P. T. Lai and J. P. Xu
- High Reliability Multi-Channel Output Voltage Switch For Multitime Programmable Memory in Standard CMOS Process.....354
 Jiasong Wang, Jiancheng Li, Hongyi Wang, Cong Li and Zhipeng Luo

Session T11	Nano-Electronics 2
Date / Time	4 August 2016 / 16:10 – 17:40

- Silicene: The Ultimate Atomic Scaling of Silicon (Invited Talk).....358 Li Tao and Deji Akinwande
- Effects of Fin Width on Performance and Reliability for N- and P-type FinFETs(Invited Talk).....361 Wen-Kuan Yeh, Wenqi Zhang, Chia-Hung Shih and Yi-Lin Yang
- Improved Characteristics for OTFT with HfO₂ Gate Dielectric by Using Chlorinated Indium Tin Oxide Gate Electrode.....365

W. M. Tang, M. G. Helander, M. T. Greiner, Z. H. Lu and W. T. Ng

Session T12	Data Converters 1
Date / Time	4 August 2016 / 16:10 – 17:40

- Design Considerations for Power Efficient Continuous-time Delta-Sigma Converters (Invited Talk).....369
 Shanthi Pavan
- A Fast-Locking All-Digital Phased-Locked Loop with a 1 ps Resolution Time-to-Digital Converter
 Using Calibrated Time Amplifier and Interpolation Digitally-Controlled-Oscillator.....375
 Hsing-Chien Chu, Yi-Hsiang Hua and Chung-Chih Hung
- A Low Power Switching Method with Variable Comparator Reference Voltage and Split Capacitor Array for SAR ADC.....379

Xiaoyong He, Junliang He, Min Cai and Zhaoxia Jing

Session F1	Data Converters 2
Date / Time	4 August 2016 / 8:30 – 9:50

- An 11b 40MS/s Charge Pump and Comparator Based Pipelined ADC with Variable Reset Voltages.....383
 Daxiang Li, Xian Tang, Zhongyi Fu, Jiangpeng Wang, Basak Debajit and Kong-Pang Pun
- An Op-amp Free SAR-VCO Hybrid ADC with Second-Order Noise Shaping.....387
 Yu Hou, Zhijie Chen, Masaya Miyahara and Akira Matsuzawa
- A 12Bit 800MS/s Time-Interleaving Pipeline ADC in 65nm CMOS.....391
 Meng Ni, Fule Li, Jia zhou, Zhijun Wang, Chun Zhang, Xian Tang and Zhihua Wang
- O Design and Implement of Baseband Circuits for a Wireless Automatic Meter Reading Application.....395
 Guanghua Wu, Hong Chen, Yanyi Meng, Xitian Long, Kun Yang, Xueping Jiang and Yuxuan Liu

Session F2	Analog 2
Date / Time	5 August 2016 / 8:30 – 9:50

A Current Detecting Circuit for Linear-mode InGaAs APD Arrays.....399
 Lixia Zhen, Ziqing Weng, Jin Wu, Tianyou Zhu, Meiya Wang and Weifeng Sun

- Cross-Coupled G_m-Boosting Technique for Two-Stage Miller-Compensated Amplifier.....403
 Ming Wai Lau, Cheuk Ho Hung, Ka Nang Leung and Wang Ling Goh
- Chip Design of Low-Power and Dual-Band Voltage Control Oscillator.....407
 Wen-Cheng Lai, Sheng-Lyang Jang and Yu-Cheng Chuang
- O Design of High-PSRR Current-Mode Bandgap Reference with Improved Frequency Compensation.....410 Lidan Wang, Chenchang Zhan, Shuangxing Zhao, Guigang Cai, Yang Liu, Qiwei Huang and Guofeng Li

Session F3	HV and Power Devices 2
Date / Time	5 August 2016 / 8:30 – 9:50

 Implantation-Free 2-Step Junction Termination Extension with 2-Space Modulated Buffer Trench Regions for UHV 4H-SiC GTO Thyristors.....414

Cai-Neng Zhou, Yan Wang, Rui-Feng Yue, Gang Dai and Jun-Tao Li

 Etched Junction Termination Extension with Floating Guard Rings and Middle Rings for Ultrahigh-Voltage 4H-SiC PiN Diodes.....418

Xiao Zou, Ruifeng Yue and Yan Wang

 Enhancement-Mode AlGaN/GaN MOS-HEMT on Silicon With Ultrathin Barrier and Diluted KOH Passivation.....422

Li-Cheng Chang, Tzung-Han Tsai, Yi-Hong Jiang, and Chao-Hsin Wu

o Modeling of Kink-Effect in RF Behaviour of GaN HEMTs using ASM-HEMT Model.....426 Sheikh Aamir Ahsan, Sudip Ghosh, Sourabh Khandelwaly and Yogesh Singh Chauhan

Session F4	Device Modeling and Simulation 2
Date / Time	5 August 2016 / 10:10 – 12:00

 Material Characterization and Device Simulation of GeSn Alloys for Field-Effect Transistors Applications (Invited Talk).....430

Renrong Liang, Lei Liu, Jing Wang and Jun Xu

 Numerical Simulations of Nonlinear Current-Voltage Characteristics of Nano-Channels: A Benchmark Study.....436

Lingzi Guo, Xin Zhu, Xingye Zhang, Zhi Ye and Yang Liu

Modeling Current Reduction for PCM Cell with Thermal Buffer Layer.....440
 Yihan Chen, Panni Wang, Mansun Chan, Xinnan Lin and Zhitong Song

Modeling of GeOI and Validation with Ge-CMOS Inverter Circuit using BSIM-IMG Industry Standard Model.....444

Harshit Agarwal, Pragya Kushwaha, Yogesh S. Chauhan, Sourabh Khandelwal, Juan P. Duarte, Yen-Kai Lin, Huan-Lin Chang, Chenming Hu, Heng Wu and Peide D. Ye

o Predictive Effective Mobility Model for FDSOI Transistors using Technology Parameters.....448

Pragya Kushwaha, Harshit Agarwal, Yogesh S. Chauhan, Mandar Bhoir, Nihar R. Mohapatra, Sourabh Khandelwal, Juan P. Duarte, Yen-Kai Lin, Huan-Lin Chang and Chenming Hu

Session F5	Sensors, Imagers and MEMS 2
Date / Time	5 August 2016 / 10:10 – 12:00

- Highly Sensitive and Functional Photodetectors Based on Silicon-On-Insulator (Invited Talk).....452
 Hiroshi Inokawa, Hiroaki Satoh and Takeo Ueta
- 3D Stacked Image Sensor with Simultaneous Global Shutter and Rolling Shutter Readout Operation.....456

Toru Kondo, Yoshiaki Takemoto, Kenji Kobayashi, Mitsuhiro Tsukimura, Naohiro Takazawa, Hideki Kato, Shunsuke Suzuki, Jun Aoki, Haruhisa Saito, Yuichi Gomi, Seisuke Matsuda and Yoshitaka Tadaki

- o Bidirectional Multi-Level Spatial Coded Exposure CMOS Capacitive TIA Pixel Design.....460 Yi Luo, Shahriar Mirabbasi and Derek Ho
- MoO₃ Nanoplatelets based Schottky Diode for Low-Noise Sensors in Harsh Envionments.....464
 Tianding Chen, Weiting Kuo, Jerry Yu and Derek Ho
- Hydrogen Sensor based on Pentacene Thin-Film Transistor.....468

 Bochang Li, P. T. Lai and Wing Man Tang

Session F6	Power Management ICs
Date / Time	5 August 2016 / 10:10 – 12:10

- A New Generation 3D Printed On-Chip Energy Storage Devices (Invited Talk).....472
 Hui Ying Yang
- A CMOS High Frequency Pulse Width Modulation Integrated Circuit.....476
 Osman Ulas Sahin and Fatih Kocer
- A 0.048ns/°C Delay Generator With Variation Self-Calibration Structure(VSCS) for HVICs.....480 Yangyang Lu, Yuming Wang, Kuo Yu, Long Miao, Jing Zhu and Weifeng Sun
- A Compact Fast-Transient Charge-Pump Boost Converter Using Hysteretic Compensated Techniques.....484
 Yuh-Shyan Hwang, Rong-Lian Shih, Po-Han Fu, Yu-Jing Hsiao, Jiann-Jong Chen and Cheng-Chieh Yu
- A High-Efficient and Wide-bandwidth Supply Modulator Using Power Switch Controlled Technique.....488
 Tai-Wei Ke, Yu-Hsuan Cheng, Yuh-Shyan Hwang, Jiann-Jong Chen, Yi-Tsen Ku and Cheng-Chieh Yu